

PATENT NUMBER

U.S. PATENT AND TRADEMARK OFFICE U.S. PATENT APPLICATION	
O.I.P.E. <u>PD</u> SCANNED <u>BAW</u> QA <u>CS1</u>	PATENT DATE

APPLICANTS

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Manufacture method for semiconductor device with small variation in mos-threshold voltage

PTO-2040
12/89

ISSUING CLASSIFICATION											
ORIGINAL				CROSS REFERENCE(S)							
CLASS		SUBCLASS		CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)						
INTERNATIONAL CLASSIFICATION											

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<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS		CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims
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<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent. No. _____ _____ _____	_____ (Primary Examiner) (Date)		ISSUE FEE	
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